

## ADD-A-PAK Generation VII Power Modules Thyristor/Diode and Thyristor/Thyristor, 45 A/60 A



**ADD-A-PAK**

<b>PRODUCT SUMMARY</b>	
$I_{T(AV)}$ or $I_{F(AV)}$	45 A/60 A

### **MECHANICAL DESCRIPTION**

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

### **FEATURES**

- High voltage
- Industrial standard package
- Low thermal resistance
- UL approved file E78996
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level



### **BENEFITS**

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

### **ELECTRICAL DESCRIPTION**

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

<b>MAJOR RATINGS AND CHARACTERISTICS</b>				
<b>SYMBOL</b>	<b>CHARACTERISTICS</b>	<b>VSK.41</b>	<b>VSK.56</b>	<b>UNITS</b>
$I_{T(AV)}$ or $I_{F(AV)}$	85 °C	45	60	A
$I_O(RMS)$	As AC switch	100	135	
$I_{TSM}$ , $I_{FSM}$	50 Hz	850	1200	
	60 Hz	890	1256	
$I^2t$	50 Hz	3.61	7.20	kA <sup>2</sup> s
	60 Hz	3.30	6.57	
$I^2\sqrt{t}$		36.1	72	kA <sup>2</sup> \sqrt{s}
$V_{RRM}$	Range	400 to 1600		V
$T_{Stg}$		- 40 to 125		°C
$T_J$				

# VSK.41.., VSK.56.. Series



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## ELECTRICAL SPECIFICATIONS

<b>VOLTAGE RATINGS</b>					
<b>TYPE NUMBER</b>	<b>VOLTAGE CODE</b>	<b>V<sub>RRM</sub>, MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V</b>	<b>V<sub>RSM</sub>, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V</b>	<b>V<sub>DRM</sub>, MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V</b>	<b>I<sub>RRM</sub>, I<sub>DRM</sub> AT 125 °C mA</b>
VSK.41 VSK.56	04	400	500	400	15
	06	600	700	600	
	08	800	900	800	
	10	1000	1100	1000	
	12	1200	1300	1200	
	14	1400	1500	1400	
	16	1600	1700	1600	

<b>ON-STATE CONDUCTION</b>									
<b>PARAMETER</b>	<b>SYMBOL</b>	<b>TEST CONDITIONS</b>			<b>VSX.41</b>	<b>VSX.56</b>	<b>UNITS</b>		
Maximum average on-state current (thyristors)	I <sub>T(AV)</sub>	180° conduction, half sine wave, T <sub>C</sub> = 85 °C			45	60	A		
Maximum average forward current (diodes)	I <sub>F(AV)</sub>								
Maximum continuous RMS on-state current, as AC switch	I <sub>O(RMS)</sub>	 or 			100	135			
Maximum peak, one-cycle non-repetitive on-state or forward current	I <sub>TSM</sub> or I <sub>FSM</sub>	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T <sub>J</sub> = T <sub>J</sub> maximum	850	1200			
		t = 8.3 ms			890	1256			
		t = 10 ms	100 % V <sub>RRM</sub> reapplied		715	1000			
		t = 8.3 ms			750	1056			
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	t = 10 ms	No voltage reapplied	Initial T <sub>J</sub> = T <sub>J</sub> maximum	3.61	7.20	kA <sup>2</sup> s		
		t = 8.3 ms			3.30	6.57			
		t = 10 ms	100 % V <sub>RRM</sub> reapplied		2.56	5.10			
		t = 8.3 ms			2.33	4.56			
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	I <sup>2</sup> $\sqrt{t}$ (1)	t = 0.1 ms to 10 ms, no voltage reapplied T <sub>J</sub> = T <sub>J</sub> maximum			36.1	72	kA <sup>2</sup> $\sqrt{s}$		
Maximum value or threshold voltage	V <sub>T(TO)</sub> (2)	Low level (3)	T <sub>J</sub> = T <sub>J</sub> maximum		1.08	0.91	V		
		High level (4)			1.12	1.02			
Maximum value of on-state slope resistance	r <sub>t</sub> (2)	Low level (3)	T <sub>J</sub> = T <sub>J</sub> maximum		4.7	4.27	mΩ		
		High level (4)			4.5	3.77			
Maximum peak on-state or forward voltage	V <sub>TM</sub>	I <sub>TM</sub> = $\pi \times I_{T(AV)}$	T <sub>J</sub> = 25 °C		1.81	1.7	V		
	V <sub>FM</sub>	I <sub>FM</sub> = $\pi \times I_{F(AV)}$							
Maximum non-repetitive rate of rise of turned on current	dI/dt	T <sub>J</sub> = 25 °C, from 0.67 V <sub>DRM</sub> , I <sub>TM</sub> = $\pi \times I_{T(AV)}$ , I <sub>g</sub> = 500 mA, t <sub>r</sub> < 0.5 μs, t <sub>p</sub> > 6 μs			150		A/μs		
Maximum holding current	I <sub>H</sub>	T <sub>J</sub> = 25 °C, anode supply = 6 V, resistive load, gate open circuit			200		mA		
Maximum latching current	I <sub>L</sub>	T <sub>J</sub> = 25 °C, anode supply = 6 V, resistive load			400	400			

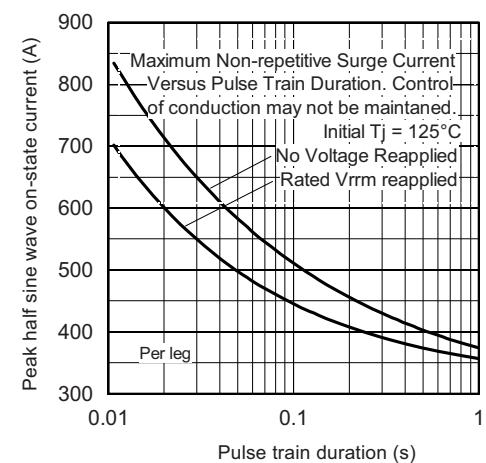
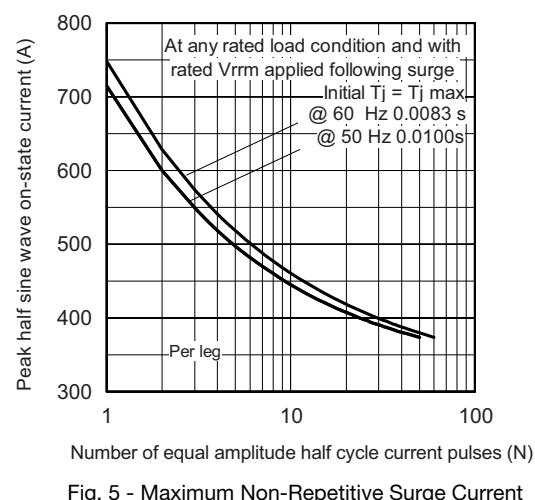
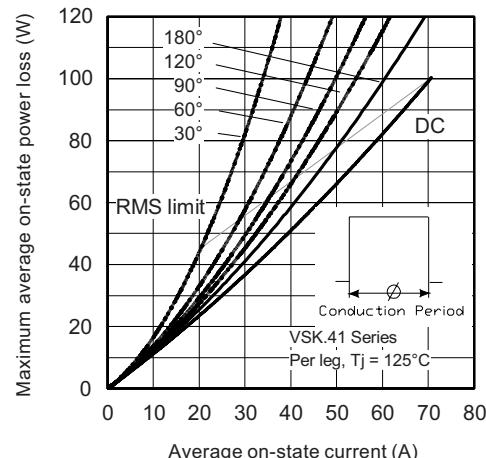
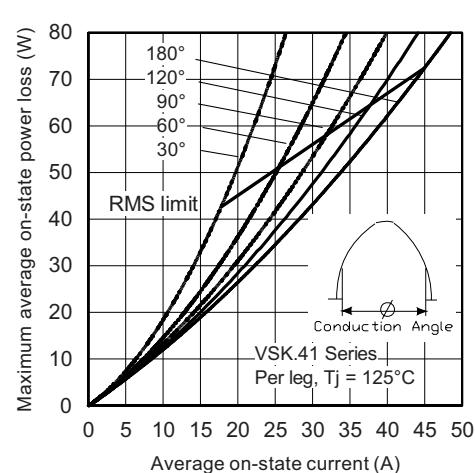
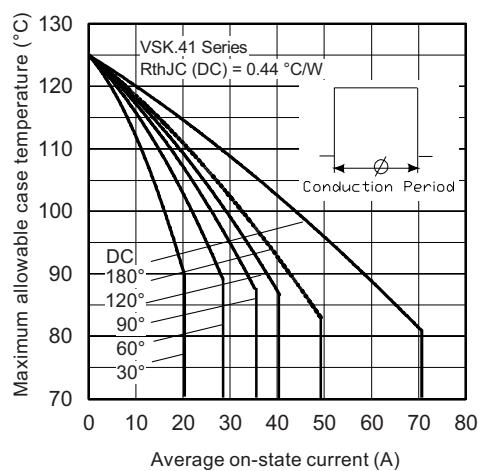
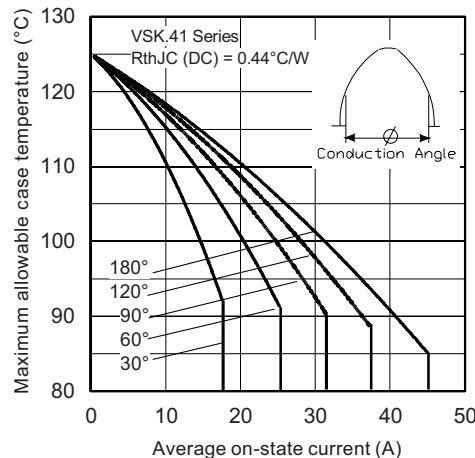
### Notes

- (1) I<sup>2</sup>t for time t<sub>x</sub> = I<sup>2</sup> $\sqrt{t} x \sqrt{t_x}$
- (2) Average power = V<sub>T(TO)</sub> × I<sub>T(AV)</sub> + r<sub>t</sub> × (I<sub>T(RMS)</sub>)<sup>2</sup>
- (3) 16.7 % × π × I<sub>AV</sub> < I < π × I<sub>AV</sub>
- (4) I > π × I<sub>AV</sub>



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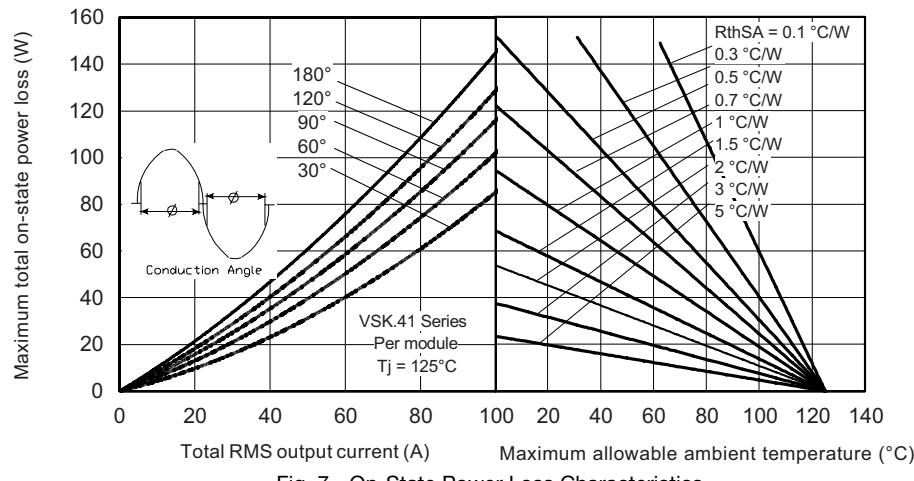


Fig. 7 - On-State Power Loss Characteristics

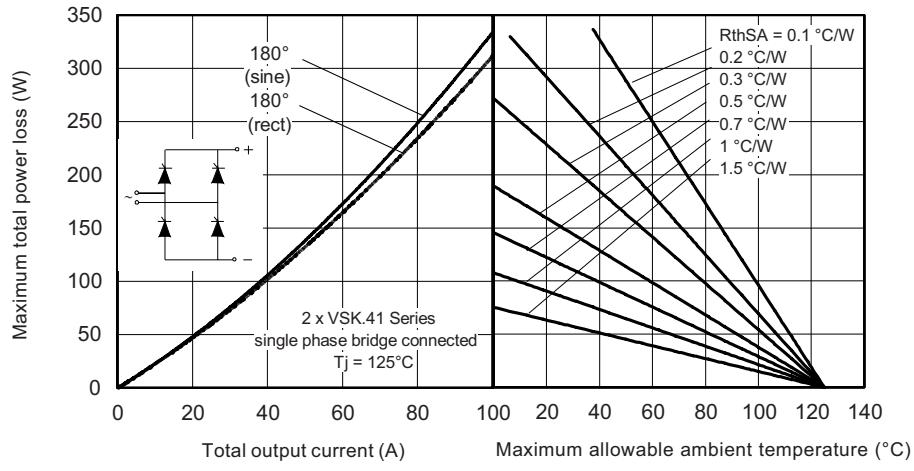


Fig. 8 - On-State Power Loss Characteristics

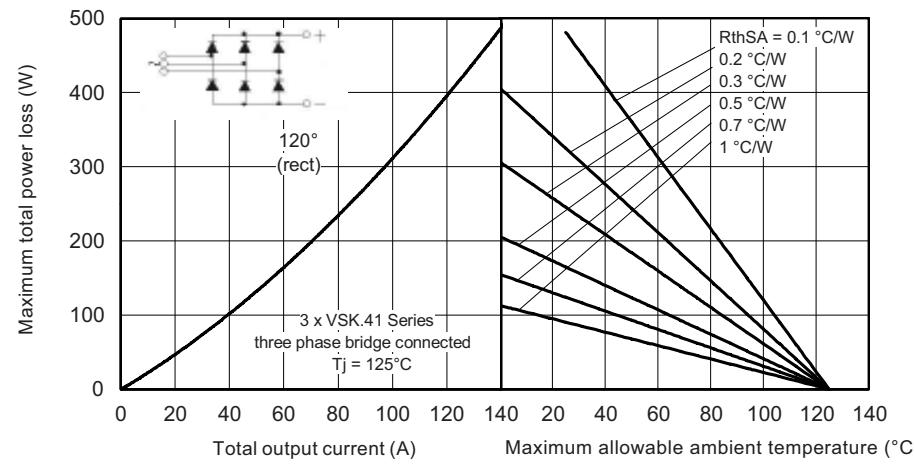


Fig. 9 - On-State Power Loss Characteristics

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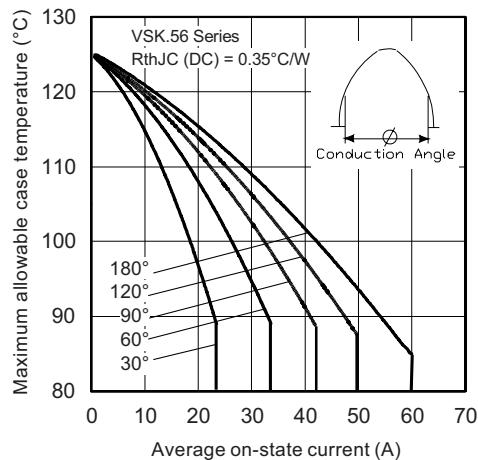


Fig. 10 - Current Ratings Characteristics

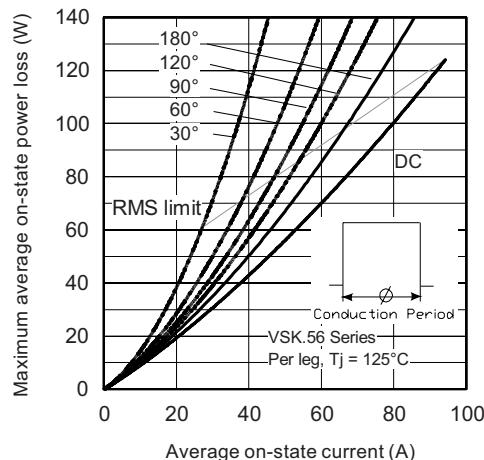


Fig. 13 - On-State Power Loss Characteristics

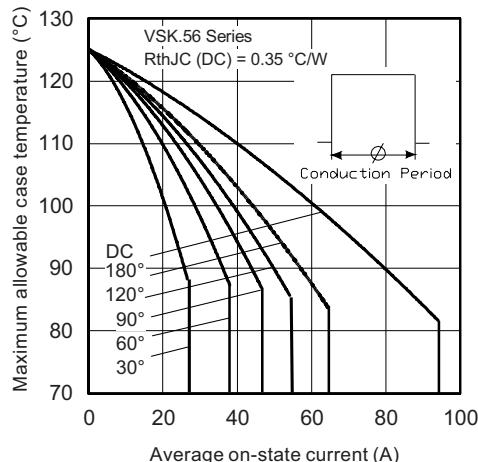


Fig. 11 - Current Ratings Characteristics

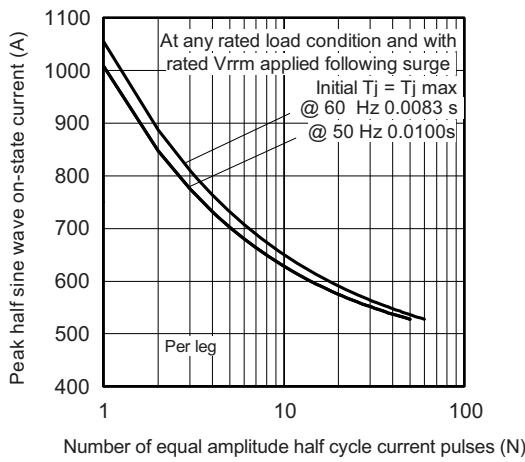


Fig. 14 - Maximum Non-Repetitive Surge Current

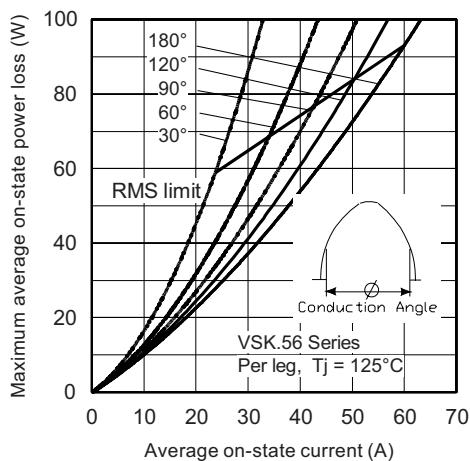


Fig. 12 - On-State Power Loss Characteristics

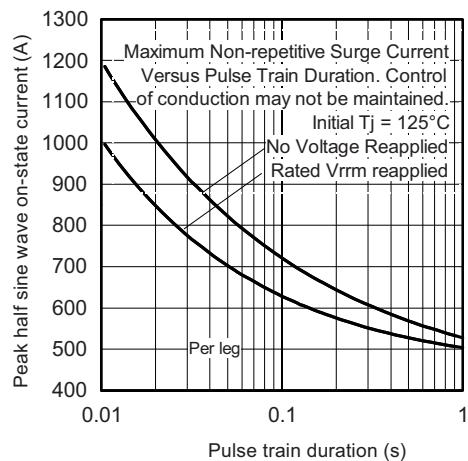


Fig. 15 - Maximum Non-Repetitive Surge Current

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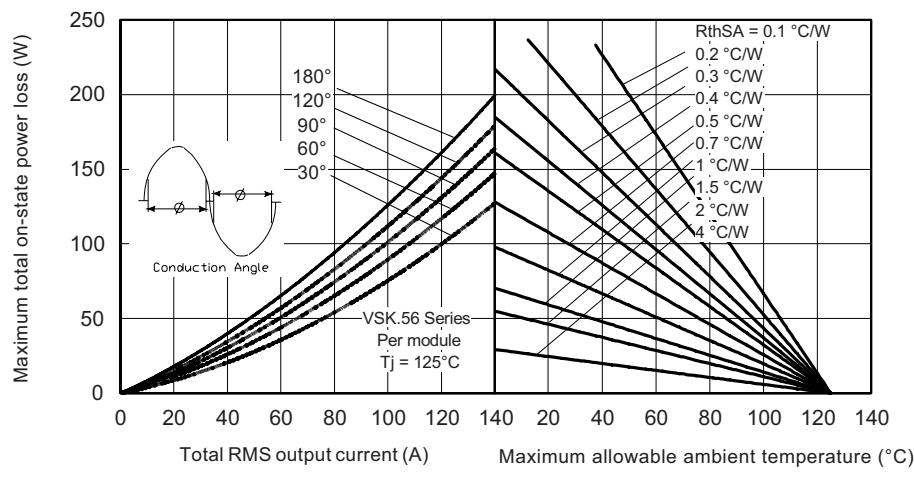


Fig. 16 - On-State Power Loss Characteristics

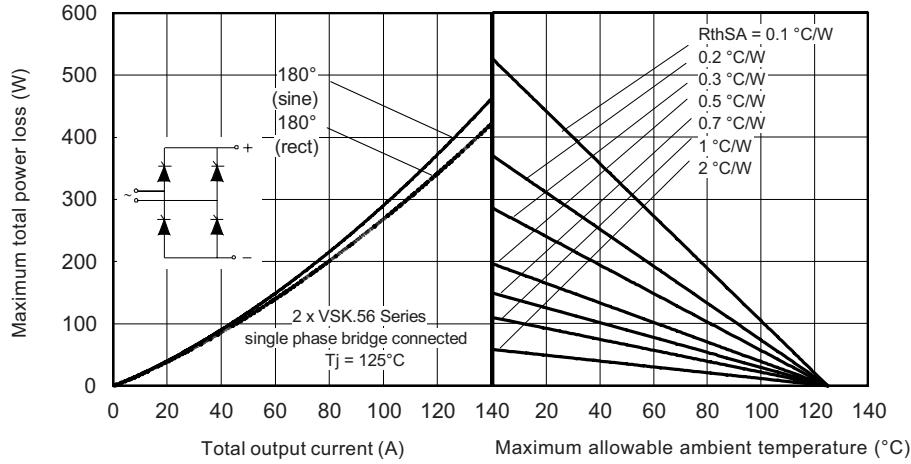


Fig. 17 - On-State Power Loss Characteristics

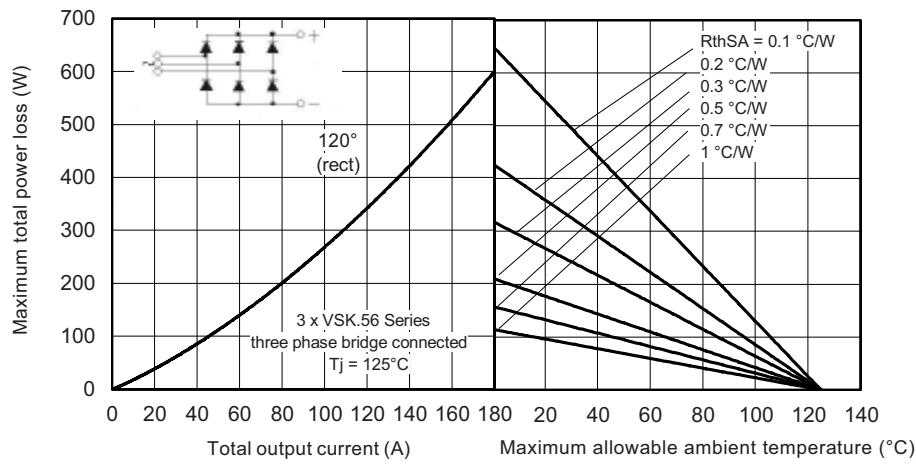


Fig. 18 - On-State Power Loss Characteristics

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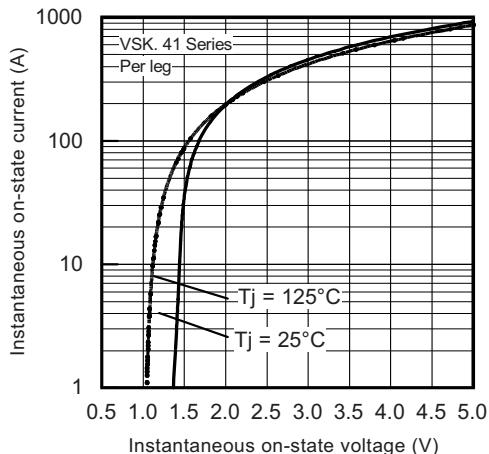


Fig. 19 - On-State Voltage Drop Characteristics

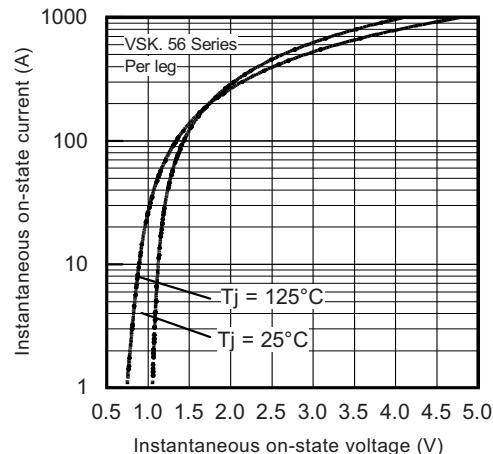


Fig. 20 - On-State Voltage Drop Characteristics

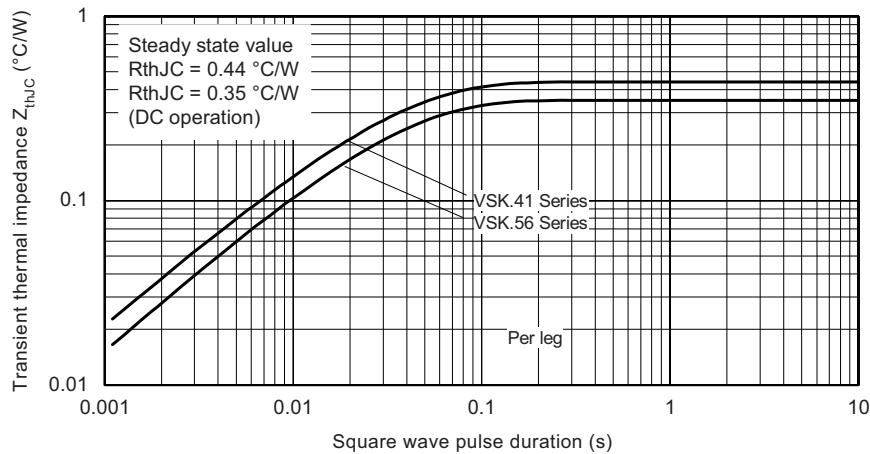


Fig. 21 - Thermal Impedance  $Z_{thJC}$  Characteristics

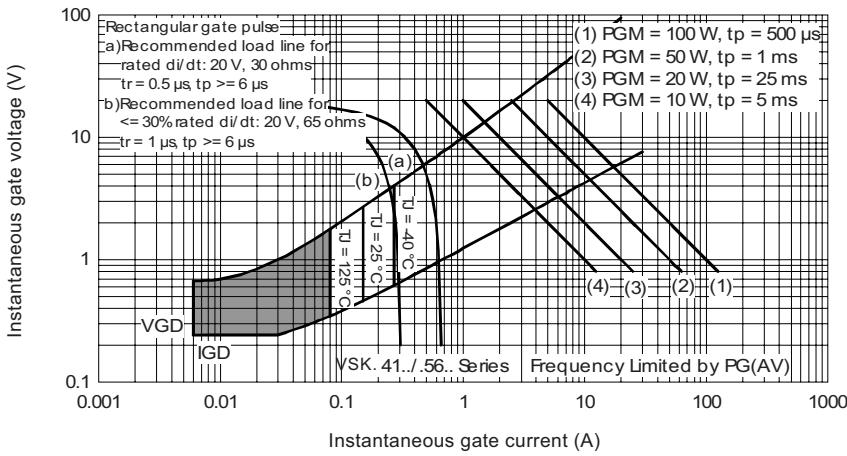


Fig. 22 - Gate Characteristics

**ORDERING INFORMATION TABLE**

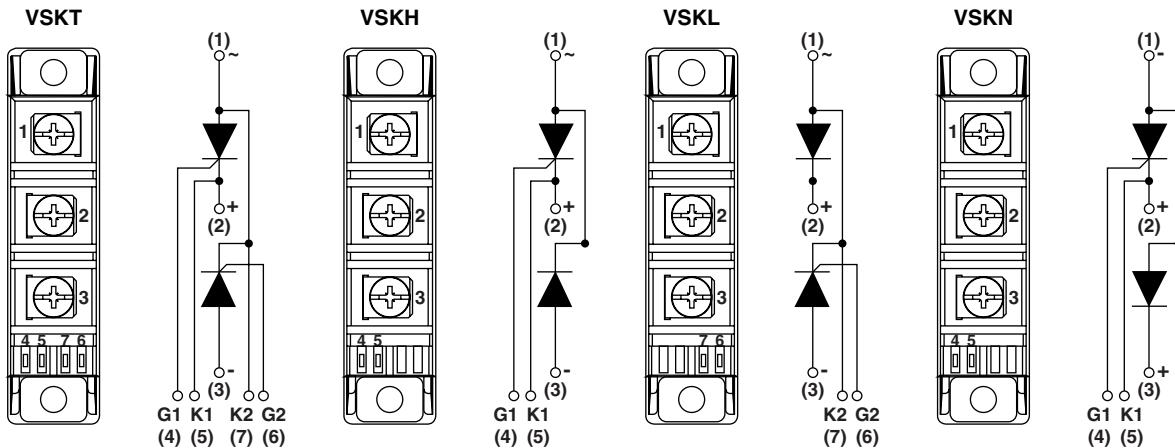
Device code	VSK	T	56	/	16
1					1
2					2
3					3
4					4

**1** - Module type  
**2** - Circuit configuration (see end of datasheet)  
**3** - Current code \_\_\_\_\_  
**4** - Voltage code (see Voltage Ratings table)

41 = 45 A  
 56 = 60 A

**Note**

- To order the optional hardware go to [www.vishay.com/doc?95172](http://www.vishay.com/doc?95172)

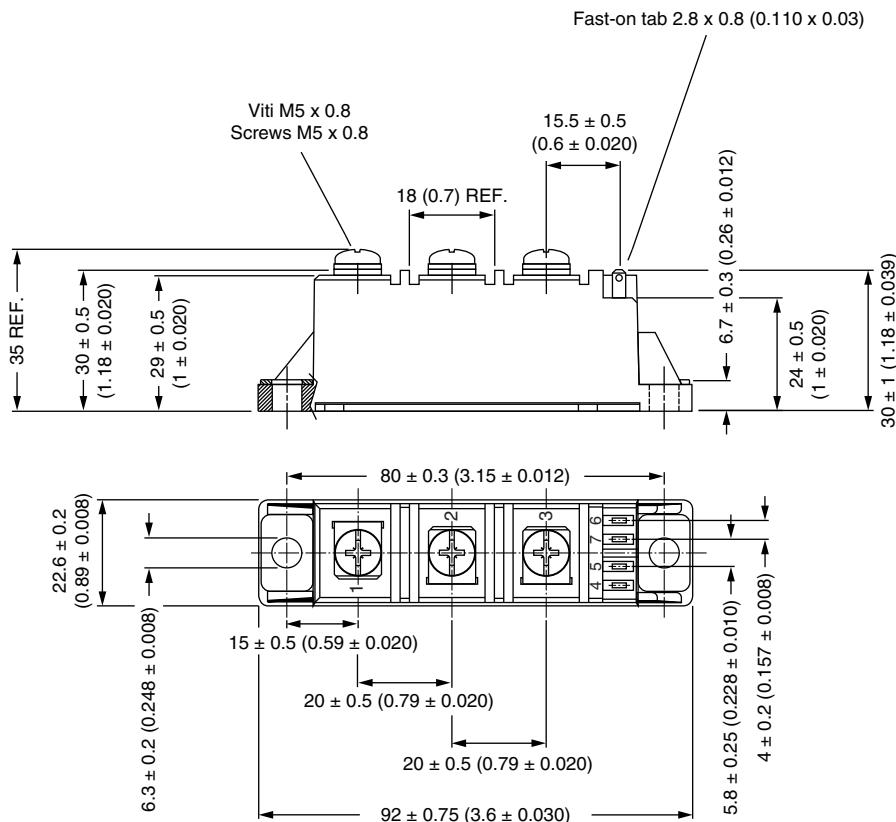
**CIRCUIT CONFIGURATION**

**LINKS TO RELATED DOCUMENTS**

Dimensions

[www.vishay.com/doc?95368](http://www.vishay.com/doc?95368)

### ADD-A-PAK Generation VII - Thyristor

#### DIMENSIONS in millimeters (inches)





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